

## Description

The PAM8304 is a mono filter-less Class-D amplifier with high SNR and differential input that helps eliminate noise. The PAM8304 supports 2.8V to 6V operation make it idea for up to 4 cells alkaline battery applications. The PAM8304 is capable of driving speaker loads as low as 3Ω speaker with a 5V supply maximizing the output power.

Features like greater than 90% efficiency and small PCB area make the PAM8304 Class-D amplifier ideal for portable applications. The output uses a filter-less architecture minimizing the number of external components and PCB area whilst providing a high performance, simple and lower cost system.

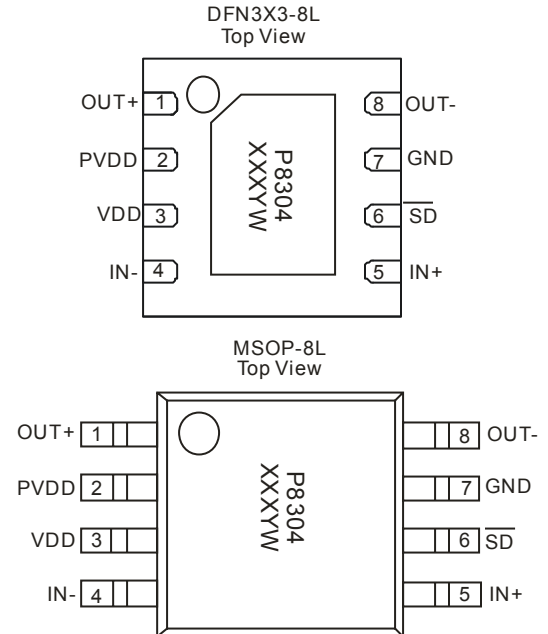
The PAM8304 features short circuit protection, thermal shutdown and under voltage lock-out.

The PAM8304 is available in DFN3030-8L and MOP-8L packages.

## Features

- Supply Voltage from 2.8V to 6.0 V
- 3Ω Driving Capability
- 3.0W@10% THD Output with a 4Ω Load and 5V Supply
- High Efficiency up to 90% @1W with an 8Ω Load
- Shutdown Current <1μA
- Superior Low Noise without Input
- Short Circuit Protection
- Thermal Shutdown
- Available in Space Saving DFN3030-8L and MSOP-8L Packages
- Pb-Free Package

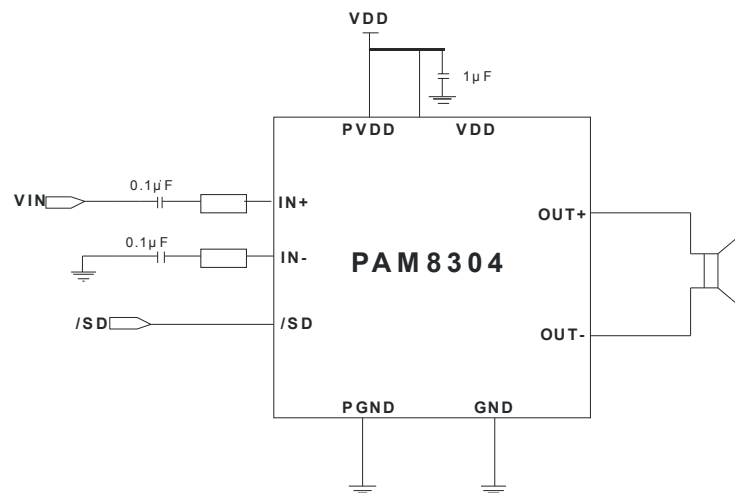
## Pin Assignments



## Applications

- MP4/MP3
- GPS
- Set-Top-Box
- Tablets/Digital Photo Frame
- Electronic Dictionary
- Portable Game Machines

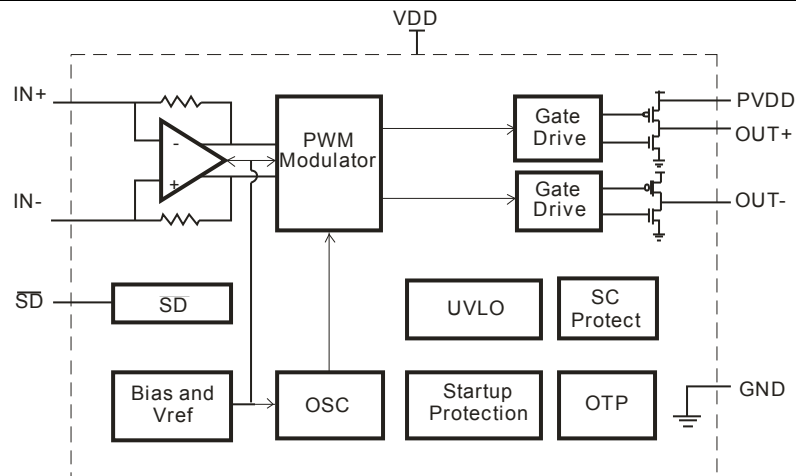
## Typical Applications Circuit



## Pin Descriptions

| Pin Name    | MSOP-8L/DFN3x3-8L | Function                      |
|-------------|-------------------|-------------------------------|
| OUT+        | 1                 | Positive BTL Output           |
| PVDD        | 2                 | Power Supply                  |
| VDD         | 3                 | Analog Power Supply           |
| IN-         | 4                 | Negative Differential Input   |
| IN+         | 5                 | Positive Differential Input   |
| /SD         | 6                 | Shutdown Terminal, Active Low |
| GND         | 7                 | Ground                        |
| OUT-        | 8                 | Negative BTL Output           |
| Exposed Pad | —                 | NC                            |

## Functional Block Diagram



## Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Parameter                     | Rating                 | Unit             |
|-------------------------------|------------------------|------------------|
| Supply Voltage (VDD)          | 6.5                    | V                |
| Input Voltage (IN+, IN-, /SD) | -0.3 to $V_{DD} + 0.3$ | V                |
| Storage Temperature           | -65 to +150            | $^\circ\text{C}$ |
| Maximum Junction Temperature  | 150                    | $^\circ\text{C}$ |

## Recommended Operating Conditions (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

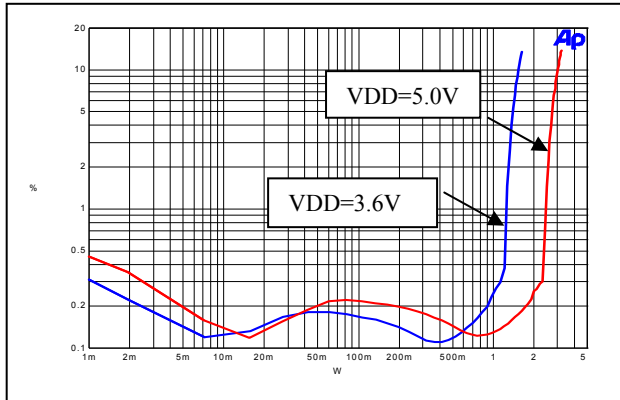
| Symbol   | Parameter                           | Min | Max  | Unit             |
|----------|-------------------------------------|-----|------|------------------|
| $V_{DD}$ | Supply Voltage                      | 2.8 | 6.0  | V                |
| $T_A$    | Operating Ambient Temperature Range | -40 | +85  | $^\circ\text{C}$ |
| $T_J$    | Junction Temperature Range          | -40 | +125 | $^\circ\text{C}$ |

**Electrical Characteristics** (@TA=25°C, VDD=5V, Gain=18dB, RL=L(33μH)+R+L(33μH), unless otherwise noted.)

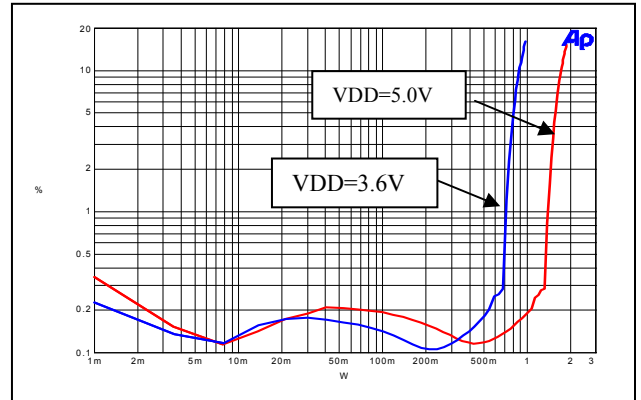
| Symbol            | Parameter                                | Test Conditions                             |                               | Min | Typ                  | Max | Unit |
|-------------------|--|---|-------------------------------|-----|----------------------|-----|------|
| VDD               | Supply Voltage                           |   |                               | 2.8 |                      | 6.0 | V    |
| Po                | Output Power                             | THD+N = 10%, f = 1kHz,<br>R = 4Ω            | VDD = 5.0V                    |     | 3.0                  |     | W    |
|                   |  |   | VDD = 3.6V                    |     | 1.5                  |     |      |
|                   |  |   | VDD = 3.2V                    |     | 1.2                  |     |      |
|                   |  | THD+N = 1%, f = 1kHz,<br>R = 4Ω             | VDD = 5.0V                    |     | 2.4                  |     | W    |
|                   |  |   | VDD = 3.6V                    |     | 1.25                 |     |      |
|                   |  |   | VDD = 3.2V                    |     | 1.0                  |     |      |
|                   |  | THD+N = 10%, f = 1kHz,<br>R = 8Ω            | VDD = 5.0V                    |     | 1.75                 |     | W    |
|                   |  |   | VDD = 3.6V                    |     | 0.90                 |     |      |
|                   |  |   | VDD = 3.2V                    |     | 0.70                 |     |      |
|                   |  | THD+N = 1%, f = 1kHz,<br>R = 8Ω             | VDD = 5.0V                    |     | 1.40                 |     | W    |
|                   |  |   | VDD = 3.6V                    |     | 0.72                 |     |      |
|                   |  |   | VDD = 3.2V                    |     | 0.60                 |     |      |
| THD+N             | Total Harmonic Distortion Plus Noise     | f = 1kHz                                    | VDD = 5.0V, Po = 1W, R = 8Ω   |     | 0.17                 |     | %    |
|                   |  |   | VDD = 3.6V, Po = 0.1W, R = 8Ω |     | 0.16                 |     |      |
|                   |  |   | VDD = 3.2V, Po = 0.1W, R = 8Ω |     | 0.14                 |     |      |
|                   |  | f = 1kHz                                    | VDD = 5.0V, Po = 0.5W, R = 4Ω |     | 0.14                 |     | %    |
|                   |  |   | VDD = 3.6V, Po = 0.2W, R = 4Ω |     | 0.16                 |     |      |
|                   |  |   | VDD = 3.2V, Po = 0.1W, R = 4Ω |     | 0.17                 |     |      |
| PSRR              | Power Supply Ripple Rejection            | VDD = 3.6V, Inputs ac-grounded with C = 1μF | f=217Hz                       |     | -68                  |     | dB   |
|                   |  |   | f=1kHz                        |     | -70                  |     |      |
|                   |  |   | f=10kHz                       |     | -67                  |     |      |
| Dyn               | Dynamic Range                            | VDD = 5V, THD = %, R = 8Ω                   | f=1kHz                        |     | 95                   |     | dB   |
| Vn                | Output Noise                             | Inputs ac-grounded                          | No A weighting                |     | 170                  |     | μV   |
|                   |  |   | A-weighting                   |     | 130                  |     |      |
| η                 | Efficiency                               | RL = 8Ω, THD = 10%                          | f=1kHz                        |     | 93                   |     | %    |
|                   |  | RL = 4Ω, THD = 10%                          |                               |     | 86                   |     |      |
| IQ                | Quiescent Current                        | VDD = 5V                                    | No Load                       |     | 5                    |     | mA   |
| I <sub>sd</sub>   | Shutdown Current                         | VDD = 2.8V to 5V                            | /SD=0V                        |     |                      | 1   | μA   |
| R <sub>dson</sub> | Static Drain-to Source On-state Resistor | High Side PMOS, I = 500mA                   | VDD=5.0V                      |     | 325                  |     | mΩ   |
|                   |  | Low Side NMOS, I = 500mA                    | VDD=5.0V                      |     | 200                  |     | mΩ   |
| f <sub>sw</sub>   | Switching Frequency                      | VDD = 2.8V to 5V                            |                               |     | 400                  |     | kHz  |
| G <sub>v</sub>    | Closed-loop Gain                         | VDD = 2.8V to 5V                            |                               |     | 300K/R <sub>in</sub> |     | V/V  |
| V <sub>os</sub>   | Output Offset Voltage                    | Input ac-ground, VDD = 5V                   |                               |     |                      | 50  | mV   |
| V <sub>IH</sub>   | SD Input High Voltage                    | VDD = 5V                                    |                               | 1.4 |                      |     | V    |
| V <sub>IL</sub>   | SD Input Low Voltage                     | VDD = 5V                                    |                               |     |                      | 1.0 |      |

**Performance Characteristics** (@TA=25°C, VDD=5V, Gain=18dB, RL=L(33μH)+R+L(33μH), unless otherwise noted.)

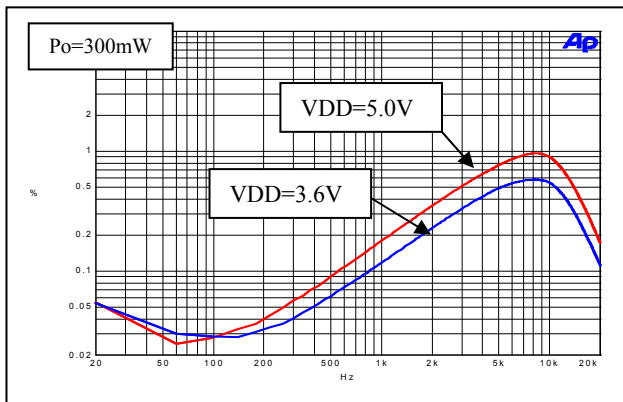
THD+N Vs. Output Power (RL=4Ω)



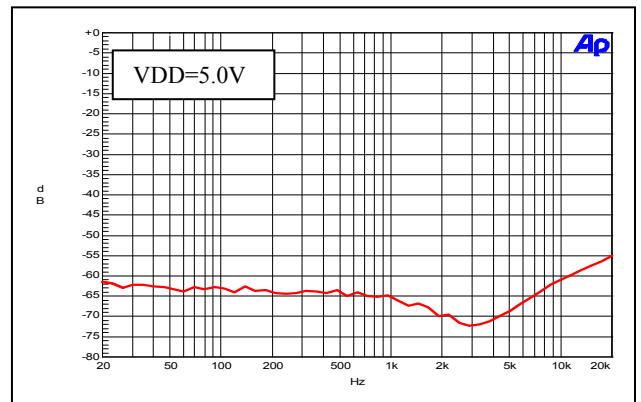
THD+N Vs. Output Power (RL=8Ω)



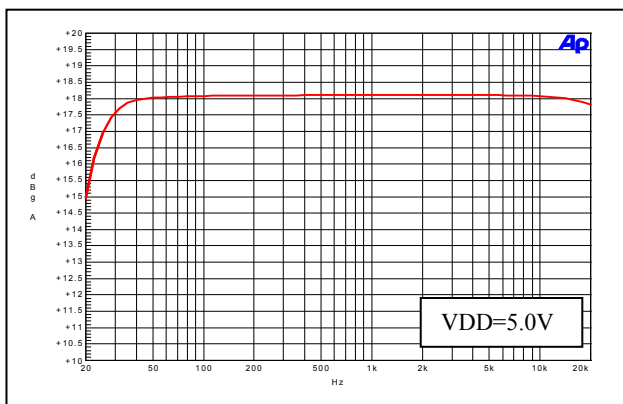
THD+N Vs. Frequency



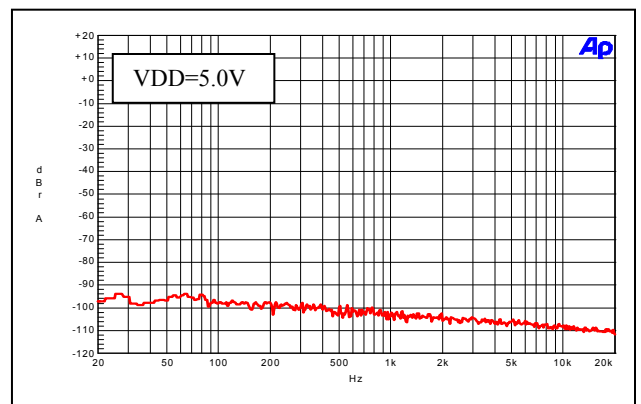
PSRR Vs. Frequency



Frequency Response

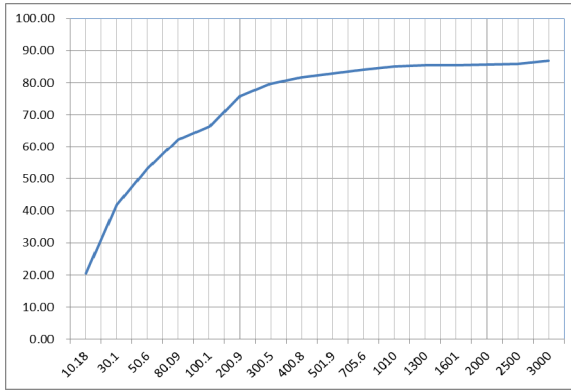


Noise Floor

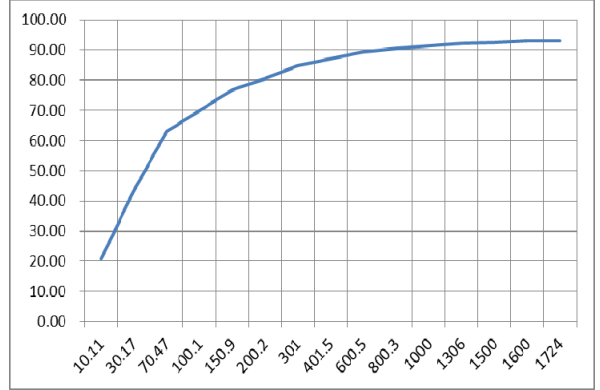


**Performance Characteristics** (@TA=25°C, VDD=5V, Gain=18dB, RL=L(33μH)+R+L(33μH), unless otherwise noted.)

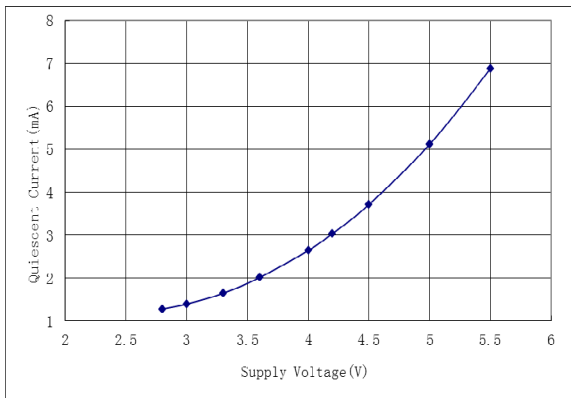
Efficiency Vs. Output Power (RL=4Ω)



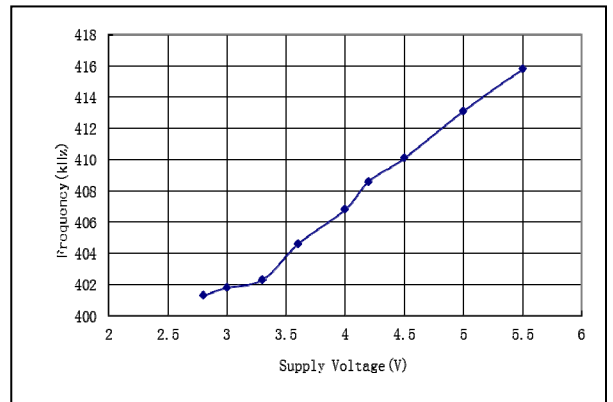
Efficiency Vs. Output Power (RL=8Ω)



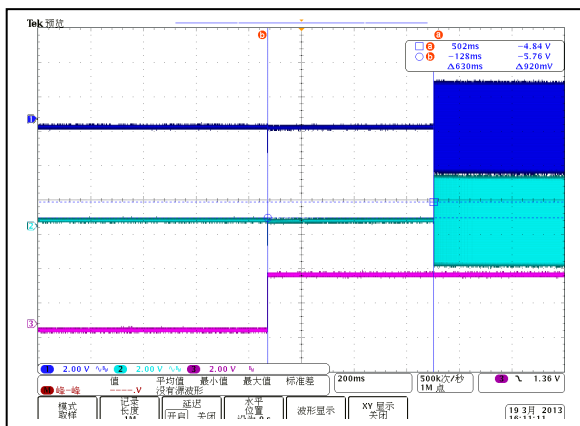
Quiescent Current Vs. Supply Voltage



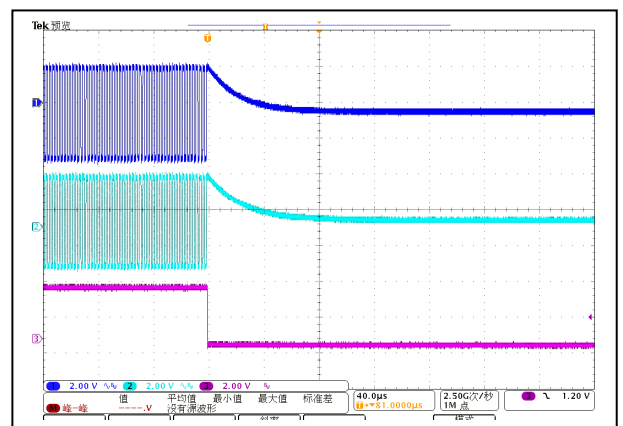
OSC Frequency Vs. Supply Voltage



Start-up Response



Shutdown Response



## Application Information

### Input Capacitors (C<sub>i</sub>)

In the typical application an input capacitor C<sub>i</sub> is required to allow the amplifier to bias the input signal to the proper DC level for optimum operation. In this case, C<sub>i</sub> and the minimum input impedance R<sub>i</sub> form a high-pass filter with the corner frequency determined in the follow equation:

$$f_c = \frac{1}{(2\pi R_i C_i)}$$

It is important to consider the value of C<sub>i</sub> as it directly affects the low frequency performance of the circuit. For example, when R<sub>i</sub> is 150kΩ and the specification calls for a flat bass response down to 150Hz. The equation is reconfigured as followed to determine the value of C<sub>i</sub>:

$$C_i = \frac{1}{(2\pi R_i f_c)}$$

When input resistance variation is considered, if C<sub>i</sub> is 7nF one would likely choose a value of 10nF. A further consideration for this capacitor is the leakage path from the input source through the input network (C<sub>i</sub>, R<sub>i</sub> and R<sub>f</sub>) to the load. This leakage current creates a DC offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason, a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used the positive side of the capacitor should face the amplifier input in most applications as the DC level is held at VDD/2, which is likely higher than the source DC level. Please note that it is important to confirm the capacitor polarity in the application.

### Decoupling Capacitor (C<sub>S</sub>)

The PAM8304 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure the output total harmonic distortion (THD) as low as possible. Power supply decoupling also prevents the oscillations causing by long lead length between the amplifier and the speaker.

Optimum decoupling is achieved by using two different types of capacitors that target different types of noise on the power supply leads. Higher frequency transients, spikes or digital hash should be filtered with a good low equivalent-series-resistance (ESR) ceramic capacitor with a value of typically 1μF. This capacitor should be placed as close as possible to the VDD pin of the device. Lower frequency noise signals should be filtered with a large ceramic capacitor of 10μF or greater. It's recommended to place this capacitor near the audio power amplifier.

### How to Reduce EMI

Most applications require a ferrite bead filter for EMI elimination as shown in Figure 1. The ferrite filter reduces EMI around 1MHz and higher. When selecting a ferrite bead it should be chosen with high impedance at high frequencies but low impedance at low frequencies.

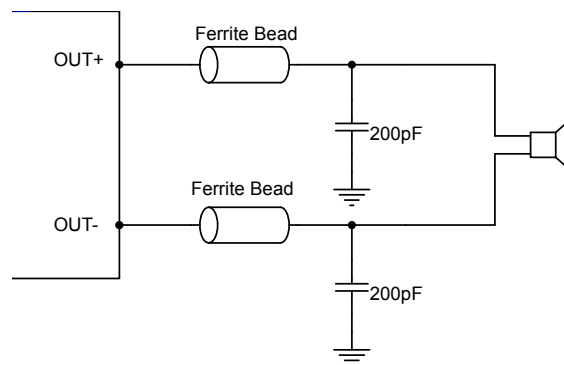


Figure 1 Ferrite Bead Filter to Reduce EMI

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## Application Information (cont.)

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### Shutdown Operation

In order to reduce power consumption while not in use the PAM8304 contains amplifier shutdown circuitry. When a logic low or ground is applied to the /SD pin the PAM8304 will enter a standby mode and supply current drawn will be minimized.

### Under Voltage Lock-out (UVLO)

The PAM8304 incorporates circuitry designed to detect low supply voltage. When the supply voltage drops to 2.0V or below, the PAM8304 goes into a state of shutdown. The device returns to normal operation only when VDD is higher than 2.5V.

### Short Circuit Protection (SCP)

The PAM8304 has short circuit protection circuitry on the outputs to prevent the device from damage when output-to-output shorts or output-to-GND shorts occur. When a short circuit occurs, the device immediately goes into shutdown state. Once the short is removed the device will be reactivated.

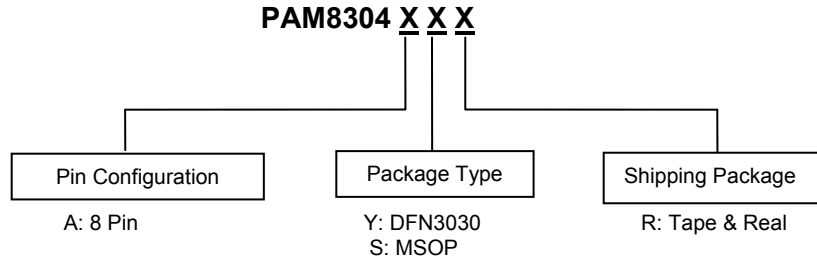
### Over Temperature Protection (OTP)

Thermal protection prevents the device from damage. When the internal die temperature exceeds a typical of 150°C the device will enter a shutdown state and the outputs are disabled. This is not a latched fault, once the thermal fault is cleared and the temperature of the die decreased by 40°C the device will restart with no external system interaction.

### Anti-POP and Anti-Click Circuitry

The PAM8304 contains circuitry to minimize turn-on and turn-off transients or “click and pops”, where turn-on refers to either power supply turn-on or device recover from shutdown mode. When the device is turned on, the amplifiers are internally muted. An internal current source ramps up the internal reference voltage. The device will remain in mute mode until the reference voltage reach half supply voltage. As soon as the reference voltage is stable, the device will begin full operation. For the best power-off pop performance, the amplifier should be set in shutdown mode prior to removing the power supply voltage.

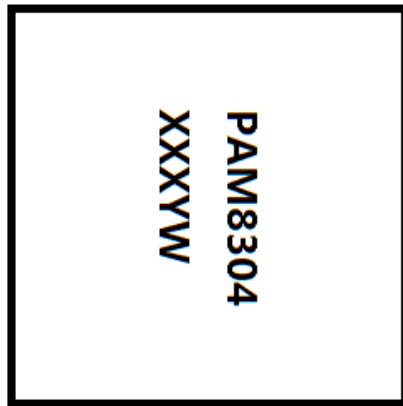
**Ordering Information**



| Part Number | Package    | Standard Package     |
|-------------|------------|----------------------|
| PAM8304AYR  | DFN3030-8L | 3,000Units/Tape&Real |
| PAM8304ASR  | MSOP-8L    | 2,500Units/Tape&Real |

**Marking Information**

DFN3030 /MOP8



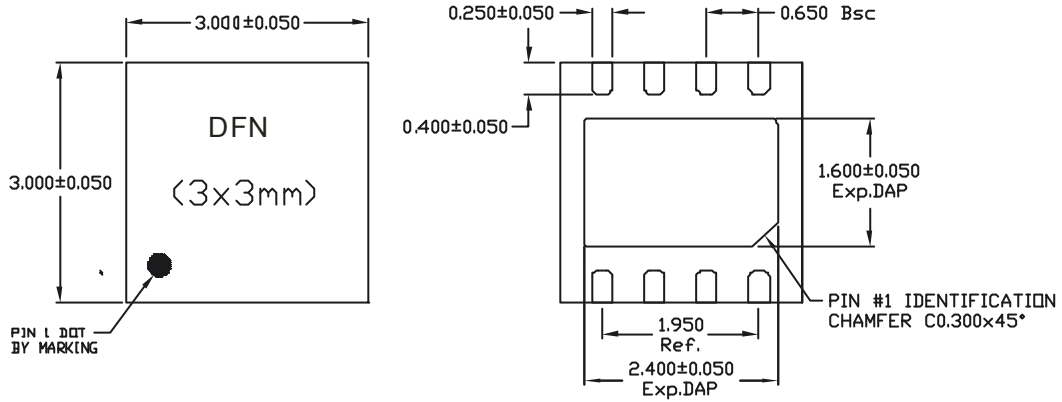
PAM8304: Product Code  
 X: Internal Code  
 Y: Year  
 W: Week

NEW PRODUCT

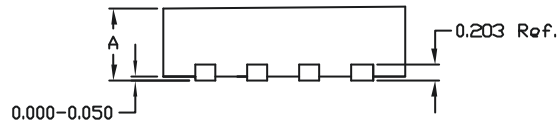


**Package Outline Dimensions** (All dimensions in mm.)

**Package: DFN3030**



|   |      |       |
|---|------|-------|
| A | MAX. | 0.800 |
|   | NOM. | 0.750 |
|   | MIN. | 0.700 |

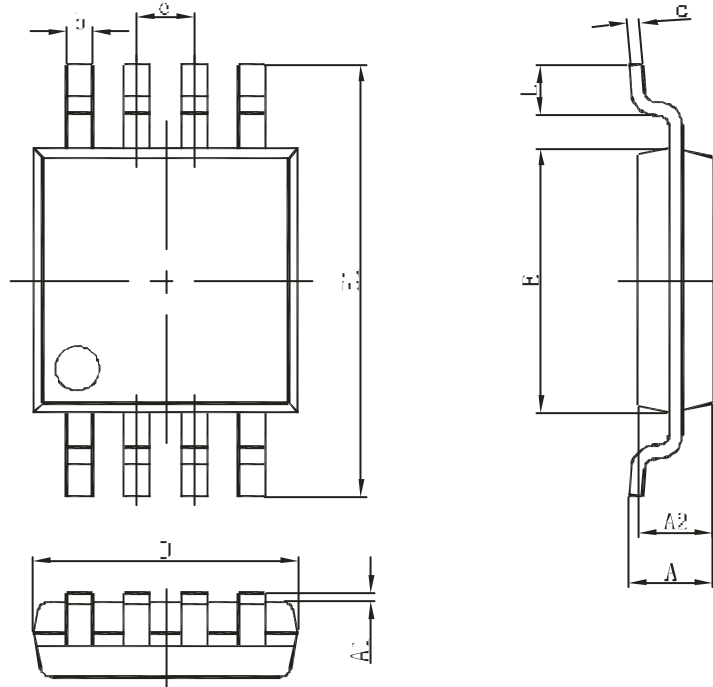


Unit: Millimeter

NEW PRODUCT

**Package Outline Dimensions** (All dimensions in mm.)

Package: MSOP



| REF | Millimeter |      |
|-----|------------|------|
|     | Min        | Max  |
| A   | --         | 1.10 |
| A1  | 0.05       | 0.15 |
| A2  | 0.78       | 0.94 |
| b   | 0.22       | 0.38 |
| c   | 0.08       | 0.23 |
| D   | 2.90       | 3.10 |
| E   | 2.90       | 3.10 |
| E1  | 4.75       | 5.05 |
| e   | 0.65BSC    |      |
| L   | 0.40       | 0.70 |

NEW PRODUCT

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